



Ultrafast Rectifier

MURB1020CTPbF MURB1020CT-1PbF

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

$$\begin{aligned} t_{rr} &= 25\text{ns} \\ I_{F(AV)} &= 10\text{Amp} \\ V_R &= 200\text{V} \end{aligned}$$

Description/ Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time. The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics. These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters		Max	Units
V_{RRM}	Peak Repetitive Peak Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current Per Leg	5	A
	Total Device, (Rated V_R), $T_C = 149^\circ\text{C}$ Total Device	10	
I_{FSM}	Non Repetitive Peak Surge Current Per Leg	50	
I_{FM}	Peak Repetitive Forward Current Per Leg	10	
T_J, T_{STG}	(Rated V_R , Square wave, 20 KHz), $T_C = 149^\circ\text{C}$ Operating Junction and Storage Temperatures	- 65 to 175	°C

Case Styles	
 D²PAK  TO-262	 TO-262

Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	200	-	-	V	$I_R = 100\mu\text{A}$
V_F	Forward Voltage	-	0.87	0.99	V	$I_F = 5\text{A}, T_J = 125^\circ\text{C}$
		-	1.02	1.20	V	$I_F = 10\text{A}, T_J = 125^\circ\text{C}$
		-	1.12	1.25	V	$I_F = 10\text{A}, T_J = 25^\circ\text{C}$
I_R	Reverse Leakage Current	-	-	10	μA	$V_R = V_R \text{ Rated}$
		-	-	250	μA	$T_J = 150^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T	Junction Capacitance	-	8	-	pF	$V_R = 200\text{V}$
L_S	Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
t_{rr}	Reverse Recovery Time	-	-	35	ns	$I_F = 1.0\text{A}, dI_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
		-	-	25		$I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{REC} = 0.25\text{A}$
		-	24	-		$T_J = 25^\circ\text{C}$
		-	35	-		$T_J = 125^\circ\text{C}$
I_{RRM}	Peak Recovery Current	-	3.3	-	A	$T_J = 25^\circ\text{C}$
		-	5.0	-		$T_J = 125^\circ\text{C}$
Q_{rr}	Reverse Recovery Charge	-	33	-	nC	$T_J = 25^\circ\text{C}$
		-	76	-		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

Parameters				Min	Typ	Max	Units	
T_J	Max. Junction Temperature Range	-	65	-	175		°C	
T_{Stg}	Max. Storage Temperature Range	-	65	-	175			
R_{thJC}	Thermal Resistance, Junction to Case Per Leg	-	-	-	5		°C/W	
R_{thJA}	Thermal Resistance, Junction to Ambient Per Leg	-	-	-	50			
R_{thCS}^{\circledR}	Thermal Resistance, Case to Heatsink	-	0.5	-				
Wt	Weight	-	2.0	-		g		
		-	0.07	-		(oz)		
Mounting Torque				6.0	-	12	Kg-cm	
				5.0	-	10	lbf.in	
Marking Device				MURB1020CT	Case style D ² Pak			
				MURB1020CT-1	Case style TO-262			

^① Mounting Surface, Flat, Smooth and Greased

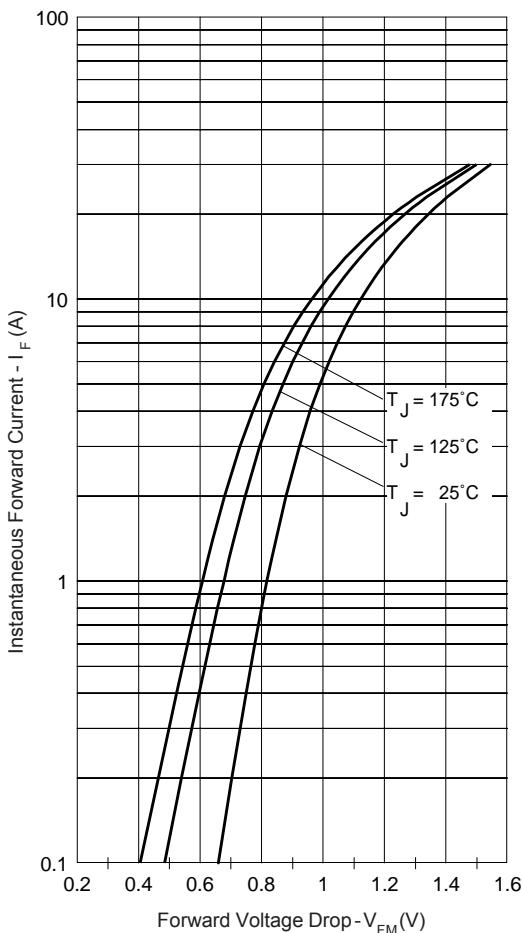


Fig. 1-Typical Forward Voltage Drop Characteristics

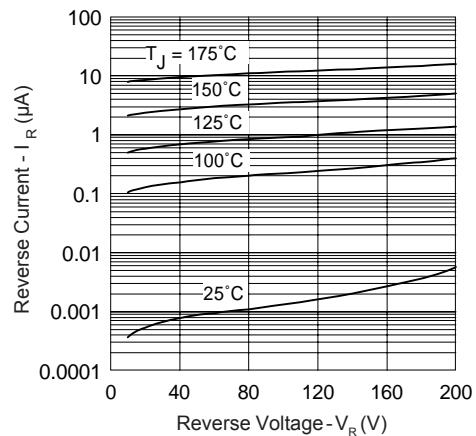


Fig. 2-Typical Values Of Reverse Current Vs. Reverse Voltage

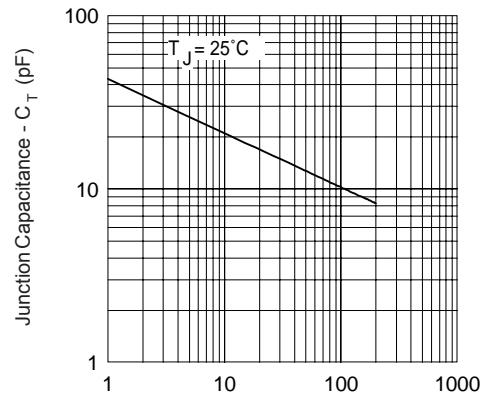


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

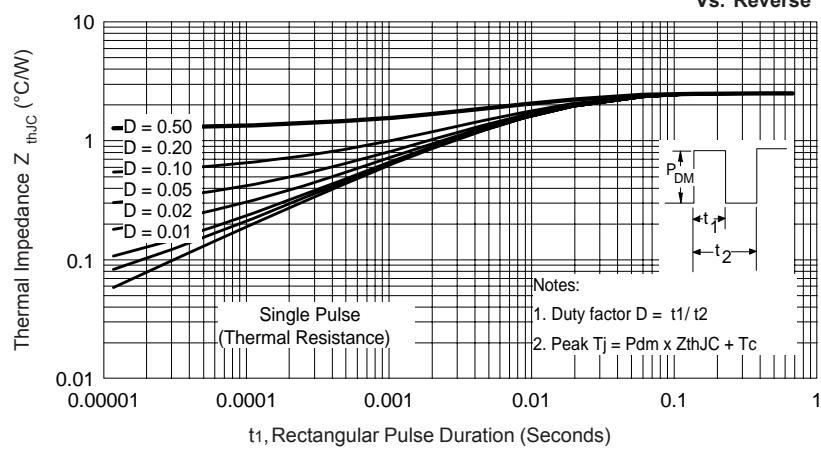


Fig. 4-Max. Thermal Impedance Z_{thJC} Characteristics

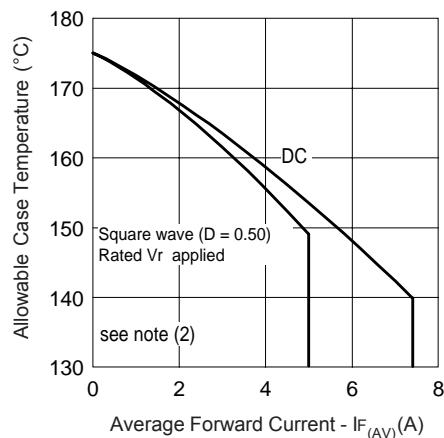


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

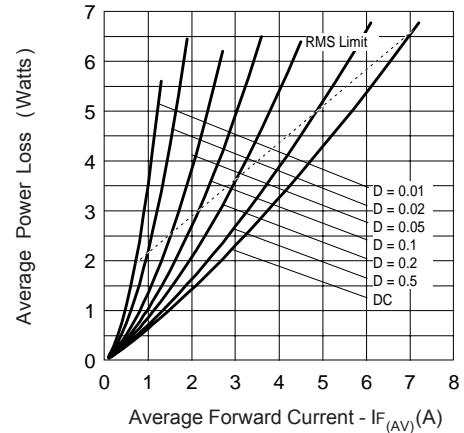
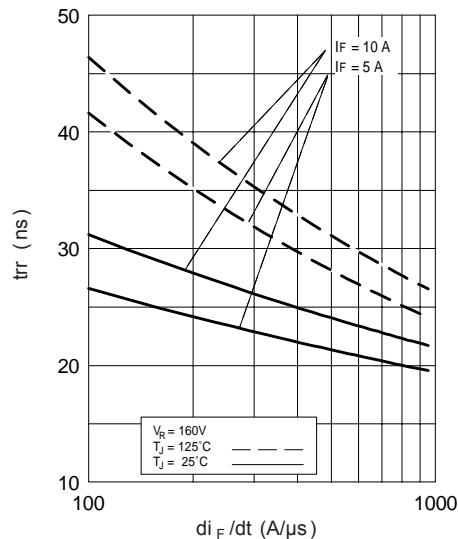
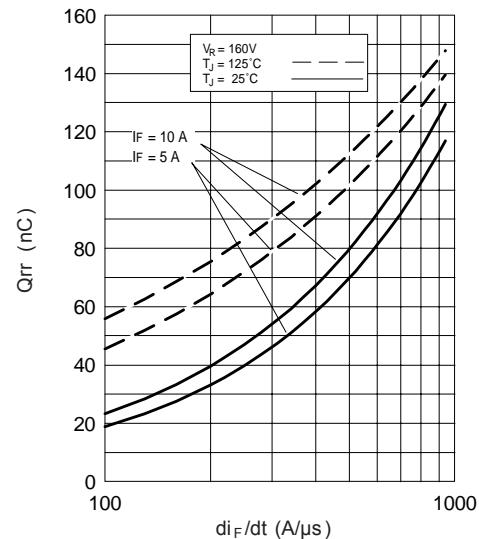


Fig. 6 - Forward Power Loss Characteristics

Fig. 7 - Typical Reverse Recovery vs. di_F/dt Fig. 8 - Typical Stored Charge vs. di_F/dt

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = \text{rated } V_R$

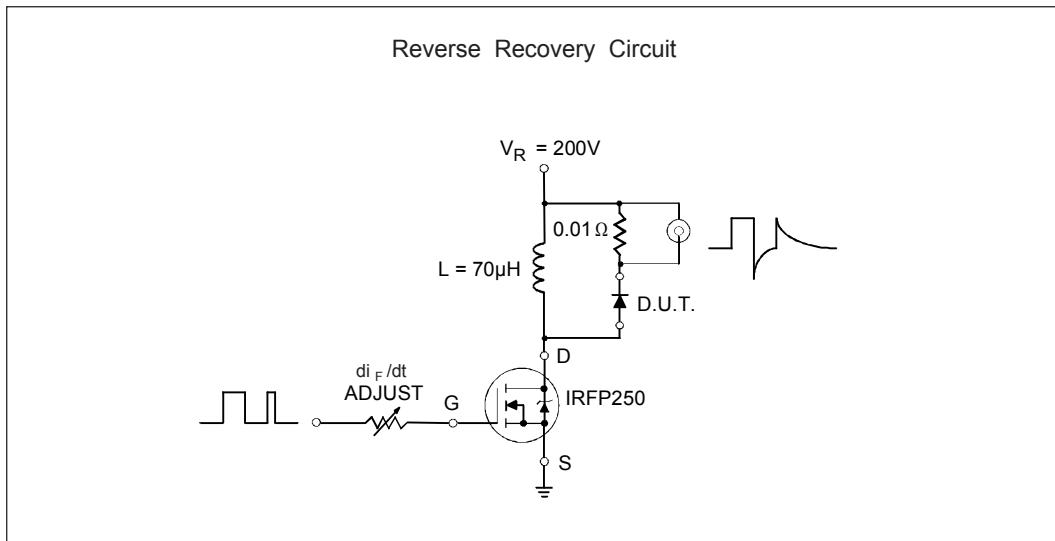


Fig. 9- Reverse Recovery Parameter Test Circuit

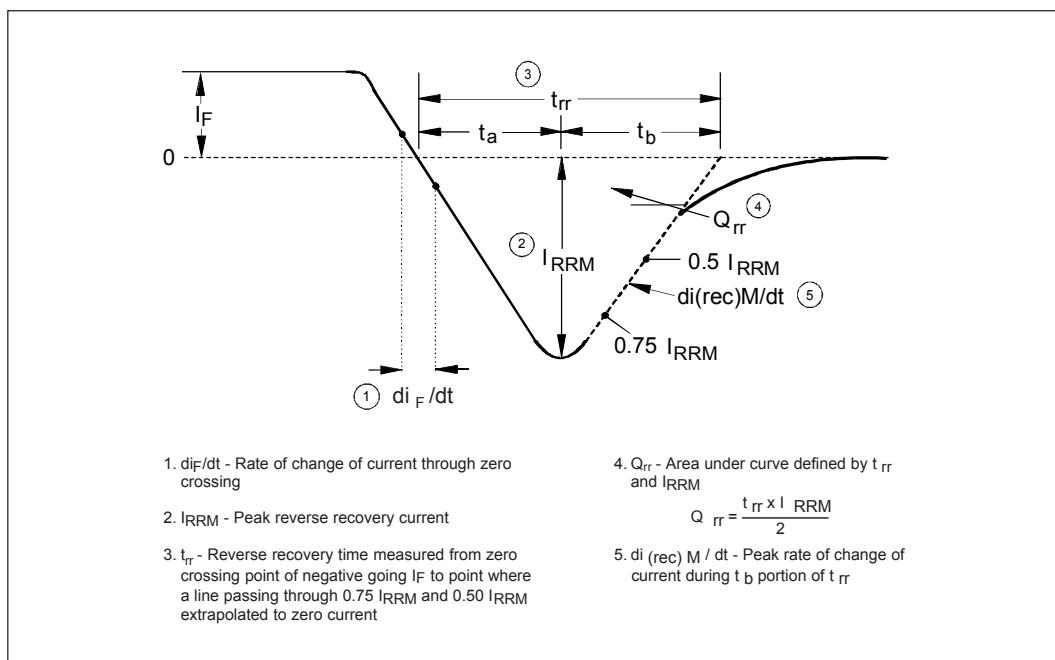
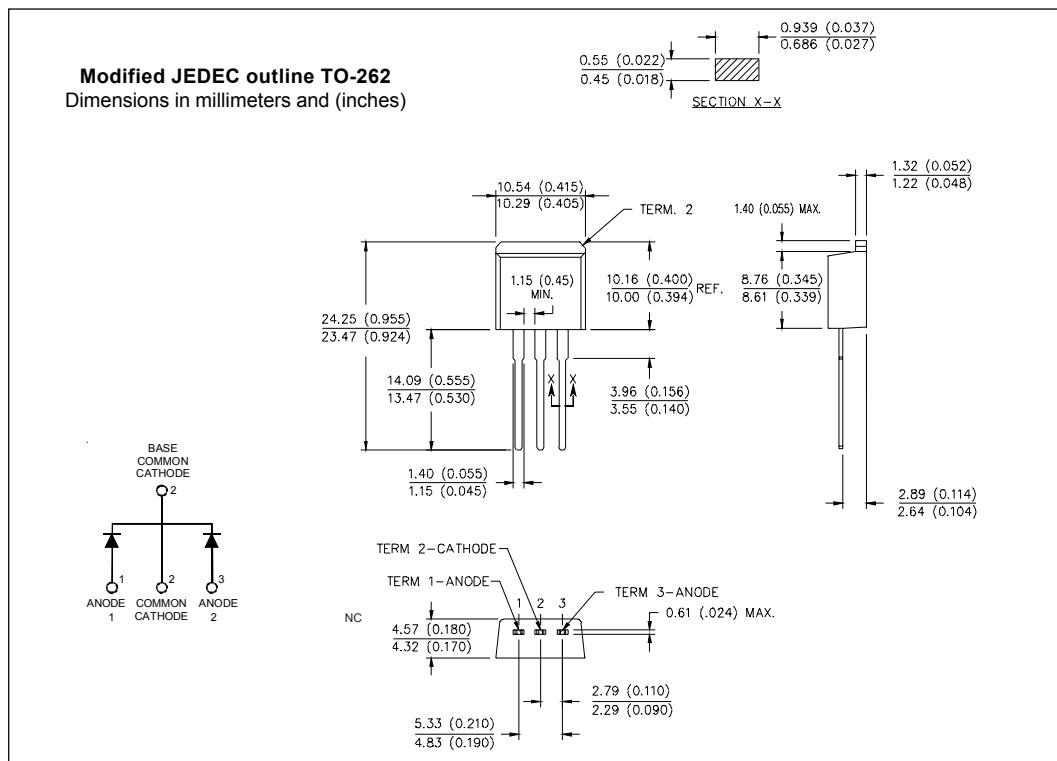
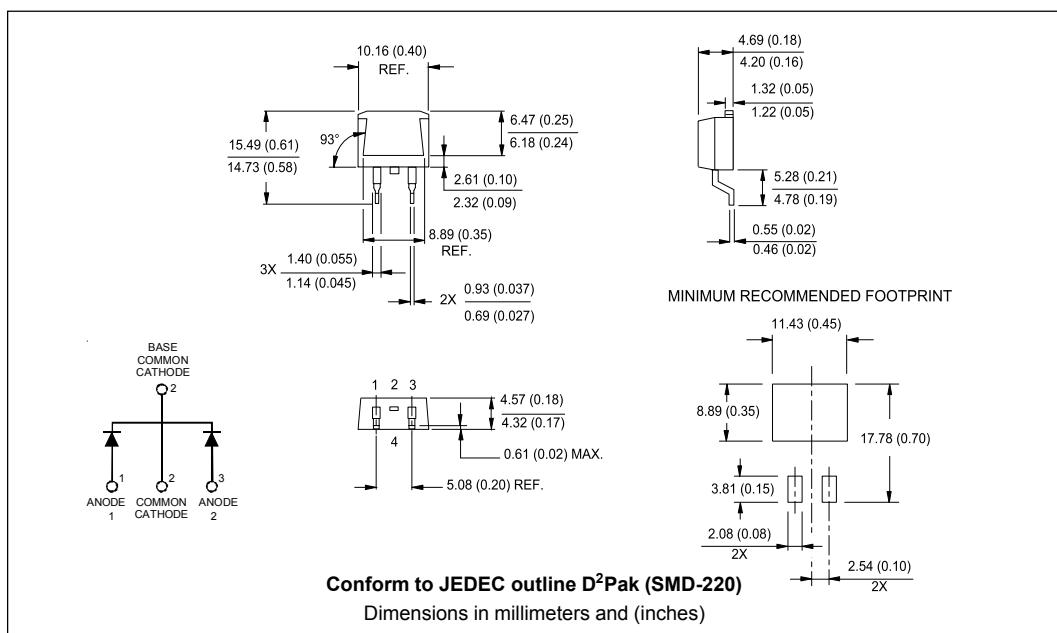


Fig. 10 - Reverse Recovery Waveform and Definitions

Outlines Table

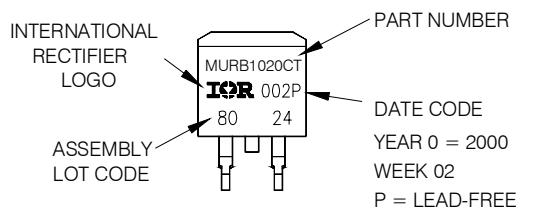


Part Marking Information

D²PAK

EXAMPLE: THIS IS A MURB1020CT
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

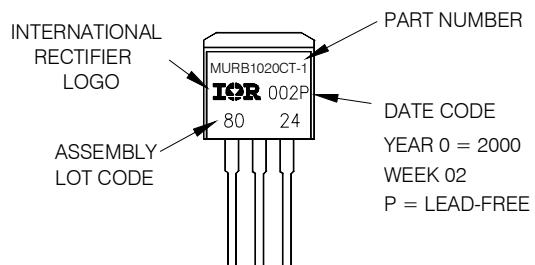
Note: "P" in assembly line
position indicates "Lead-Free"



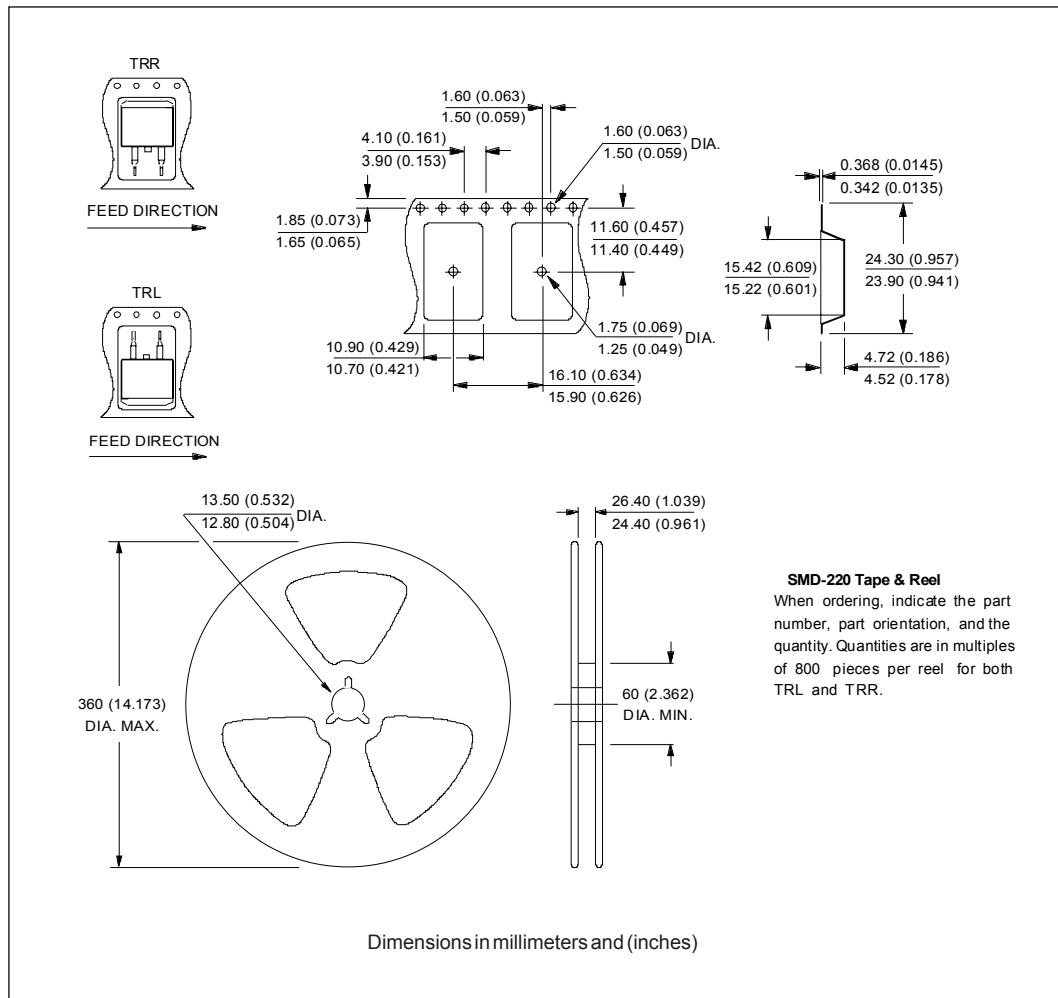
TO-262

EXAMPLE: THIS IS A MURB1020CT-1
LOT CODE 8024
ASSEMBLED ON WW 02, 2000

Note: "P" in assembly line
position indicates "Lead-Free"



Tape & Reel Information



Ordering Information Table

Device Code	MUR	B	10	20	CT	-1	TRL	PbF
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
1	- Ultrafast MUR Series							
2	- B = D ² Pak/ TO-262							
3	- Current Rating (10 = 10A)							
4	- Voltage Rating (20 = 200V)							
5	- CT = Center Tap (Dual) TO-220 /D ² PAK/ TO-262							
6	- -1 = TO-262							
7	- • none = Tube (50 pieces) • TRL = Tape & Reel (Left Oriented, for D ² PAk package) • TRR = Tape & Reel (Right Oriented, for D ² PAk package)							
8	- • none = Standard Production • PbF = Lead-Free							

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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